

 	<h2 style="color: red;">FQD7P20TF</h2>
	<p><b>Hersteller-Teilenummer:</b> FQD7P20TF</p> <p><b>Hersteller / Marke:</b> Fairchild/ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 200V 5.7A DPAK</p> <p><b>Datenblätter:</b> <a href="#">1.FQD7P20TF.pdf</a> <a href="#">2.FQD7P20TF.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 32363 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQD7P20TF
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET P-CH 200V 5.7A DPAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	32363 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	D-Pak
Verlustleistung (max)	2.5W (Ta), 55W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	5.7A (Tc)
Rds On (Max) @ Id, Vgs	690 mOhm @ 2.85A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	770pF @ 25V
Verpackung	Tape & Reel (TR)

FQD7P20TF ist neu im Original, Suche FQD7P20TF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQD7P20TF Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQD7P20TF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>FQD7P20TM</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 200V 5.7A DPAK</p>	 <p><b>FQD7P10TF</b> FAI FQD7P10TF FAI</p>	 <p><b>FQD7P06TM_NB82050</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 5.4A DPAK</p>	 <p><b>FQD7P20TF</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 200V 5.7A DPAK</p>
 <p><b>FQD7P20TM_F080</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 200V 5.7A DPAK</p>	 <p><b>FQD7P20</b> Original FQD7P20 Original</p>	 <p><b>FQD7P20TM_F080</b> Fairchild/ON Semiconductor MOSFET P-CH 200V 5.7A DPAK</p>	 <p><b>FQD7P20TM</b> Fairchild/ON Semiconductor MOSFET P-CH 200V 5.7A DPAK</p>

### heiße Teile

Mehr

<a href="#">FQD6P25TM</a>	<a href="#">FQD6P25TM</a>	<a href="#">FQD7N10L</a>	<a href="#">FQD7N10LTF</a>	<a href="#">FQD7N10LTF</a>
<a href="#">FQD7N10LTM</a>	<a href="#">FQD7N10LTM</a>	<a href="#">FQD7N10TF</a>	<a href="#">FQD7N10TM</a>	<a href="#">FQD7N10TM</a>
<a href="#">FQD7N20L</a>	<a href="#">FQD7N20LTF</a>	<a href="#">FQD7N20LTF</a>	<a href="#">FQD7N20LTM</a>	<a href="#">FQD7N20LTM</a>
<a href="#">FQD7N20TF</a>	<a href="#">FQD7N20TF</a>	<a href="#">FQD7N20TM</a>	<a href="#">FQD7N20TM</a>	<a href="#">FQD7N30TM</a>
<a href="#">FQD7N30TM</a>	<a href="#">FQD7P06TF</a>	<a href="#">FQD7P06TF</a>	<a href="#">FQD7P06TM</a>	<a href="#">FQD7P06TM</a>
<a href="#">FQD7P06TM_F080</a>	<a href="#">FQD7P06TM_F080</a>	<a href="#">FQD7P06TM_NB82050</a>	<a href="#">FQD7P06TM_NB82050</a>	<a href="#">FQD7P10TF</a>
<a href="#">FQD7P20TF</a>	<a href="#">FQD7P20TM</a>	<a href="#">FQD7P20TM</a>	<a href="#">FQD7P20TM_F080</a>	<a href="#">FQD7P20TM_F080</a>
<a href="#">FQD8P10TF</a>	<a href="#">FQD8P10TF</a>	<a href="#">FQD8P10TF_NB82052</a>	<a href="#">FQD8P10TF_NB82052</a>	<a href="#">FQD8P10TM</a>
<a href="#">FQD8P10TM</a>	<a href="#">FQD8P10TM_</a>	<a href="#">FQD8P10TM_F080</a>	<a href="#">FQD8P10TM_F080</a>	<a href="#">FQD8P10TM_F085</a>
<a href="#">FQD8P10TM_SB82052</a>	<a href="#">FQD8P10TM_SB82052</a>	<a href="#">FQD9N08L</a>	<a href="#">FQD9N25TM</a>	<a href="#">FQD9N25TM</a>

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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